TOSHIBA Field Effect Transistor Silicon N/P Channel MOS Type(π -MOSVI)

SSM6L09FU

Power Management Switch High Speed Switching Applications

- Small package
- Low on-resistance

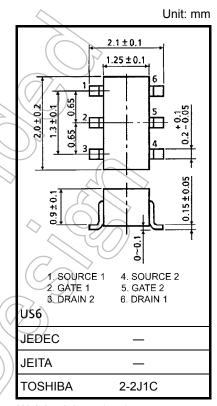
Q1: RDS(ON) = 0.7 Ω (max) (@V_{GS} = 10 V) Q2: RDS(ON) = 2.7 Ω (max) (@V_{GS} = -10 V)

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V _{DSS}	30	R.
Gate-Source voltage		V _{GSS}	±20	(Y)
Drain current	DC	I _D	400	mA
	Pulse	I _{DP}	800	

Q2 Absolute Maximum Ratings (Ta = 25°C)

Symbol Rating Unit
V _{DSS} –30 V
V _{GSS} ±20 V
ID -200 mA



Weight: 6.8 mg (typ.)

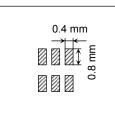
Absolute Maximum Ratings (Q1, Q2 common) (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power dissipation	P _D (Note 1)	300	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

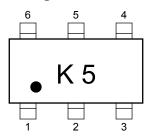
Note 1: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 mm, Cu Pad: 0.32 mm $^2 \times$ 6)



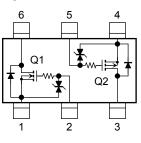
Start of commercial production 2001-02

<u>TOSHIBA</u>

Marking (top view)



Equivalent Circuit



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

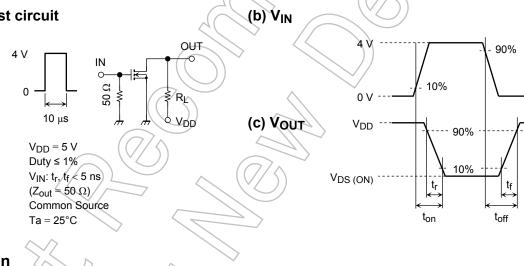
Q1 Electrical Characteristics (Ta = 25°C)

Charao	cteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Gate leakage curren	t	I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0$	_	_	±1	μA
Drain-Source breakdown voltage		V (BR) DSS	I _D = 1 mA, V _{GS} = 0	30	_	_	V
Drain cut-off current		IDSS	$V_{DS} = 30 V, V_{GS} = 0$		_	1	μA
Gate threshold voltage	ge	V _{th}	$V_{DS} = 5 \text{ V}, \text{ I}_{D} = 0.1 \text{ mA}$	1.1	_	1.8	V
Forward transfer adr	nittance	Y _{fs}	$V_{DS} = 5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$ (Note2)	270			mS
Drain-Source on-resistance		R _{DS} (ON)	I _D = 200 mA, V _{GS} = 10 V (Note2)	52	0.5	0.7	Ω
			I _D = 200 mA, V _{GS} = 4 V (Note2)	7 A	0.8	1.2	
			I _D = 200 mA, V _{GS} = 3.3 V (Note2)	92	1.0	1.7	
Input capacitance		C _{iss}		> —	20		pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 5 V, V _{GS} = 0, f = 1 MHz	_	Z	I	pF
Output capacitance		C _{oss}	$\langle \rangle$	_	16	Þ	pF
Switching time	Turn-on time	t _{on}	V _{DD} = 5 V, I _D = 200 mA,	- /	72	-	
	Turn-off time	t _{off}	$V_{GS} = 0$ to 4 V	, -(C	68	_	ns

Note2: Pulse test

Switching Time Test Circuit

(a) Test circuit



Precaution

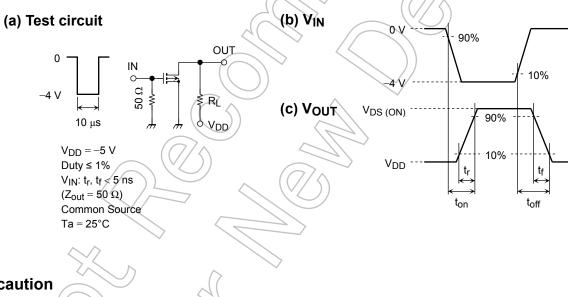
 V_{th} can be expressed as the voltage between the gate and source when the low operating current value is ID = 0.1 mA for this product. For normal switching operation, VGS (on) requires a higher voltage than Vth and VGS (off) requires a lower voltage than Vth. (The relationship can be established as follows: VGS (off) < Vth < VGS (on).) Be sure to take this into consideration when using the device.

Q2 Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Gate leakage current	t	I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0$	_	—	±1	μA	
Drain-Source breakdown voltage		V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0$		_		V	
Drain cut-off current		I _{DSS}	$V_{DS} = -30 V, V_{GS} = 0$	1	_	-1	μA	
Gate threshold voltage	ge	V _{th}	$V_{DS} = -5 \text{ V}, \text{ I}_{D} = -0.1 \text{ mA}$	71.1	_	-1.8	V	
Forward transfer adm	nittance	Y _{fs}	$V_{DS} = -5 V$, $I_D = -100 mA$ (Note3)	115		_	mS	
Drain-Source on-resistance		R _{DS (ON)}	I _D = -100 mA, V _{GS} = -10 V (Note3)		2.1	2.7		
			$I_D = -100 \text{ mA}, V_{GS} = -4 \text{ V}$ (Note3)	7 ()	3.3	4.2	Ω	
			$I_D = -100 \text{ mA}, V_{GS} = -3.3 \text{ V(Note3)}$	92	4.0	6.0	1	
Input capacitance		C _{iss}	$V_{DS} = -5 V, V_{GS} = 0, f = 1 MHz$	> _	22	_	pF	
Reverse transfer cap	nsfer capacitance C_{rss} $V_{DS} = -5 V$, $V_{GS} = 0$, $f = 1 MHz$ - 5		5		pF			
Output capacitance		C _{oss}	$V_{DS} = -5 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	_14	Ś	pF	
Switching time	Turn-on time	t _{on}	$V_{DD} = -5 V, I_D = -100 mA,$	(85			
	Turn-off time	t _{off}	$V_{GS} = 0$ to -4 V	_((85	< -	ns	

Note3: Pulse test

Switching Time Test Circuit

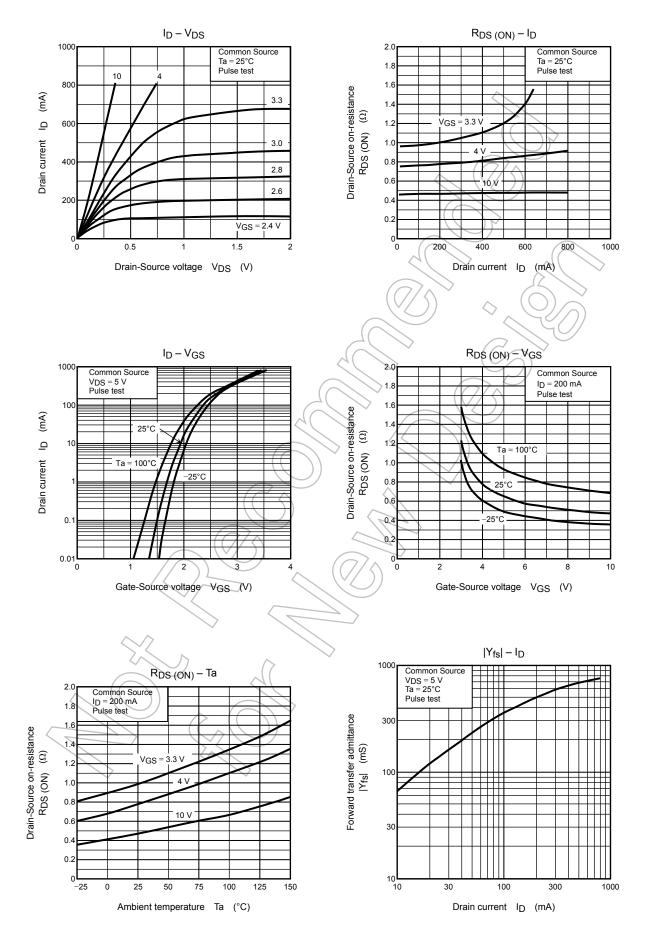


Precaution

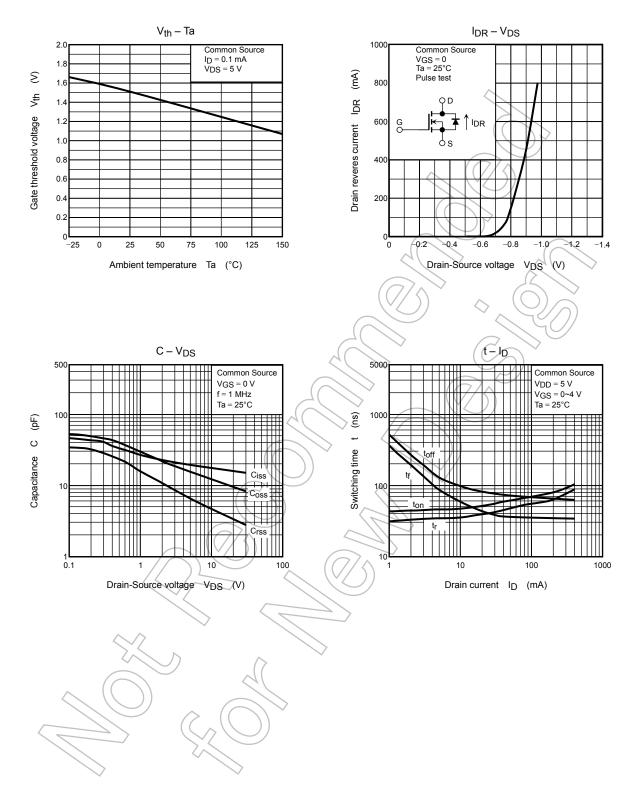
 V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = -0.1$ mA for this product. For normal switching operation, VGS (on) requires higher voltage than Vth and VGS (off) requires lower voltage than V_{th} . (Relationship can be established as follows: V_{GS} (off) < V_{th} < V_{GS} (on))

Please take this into consideration for using the device.

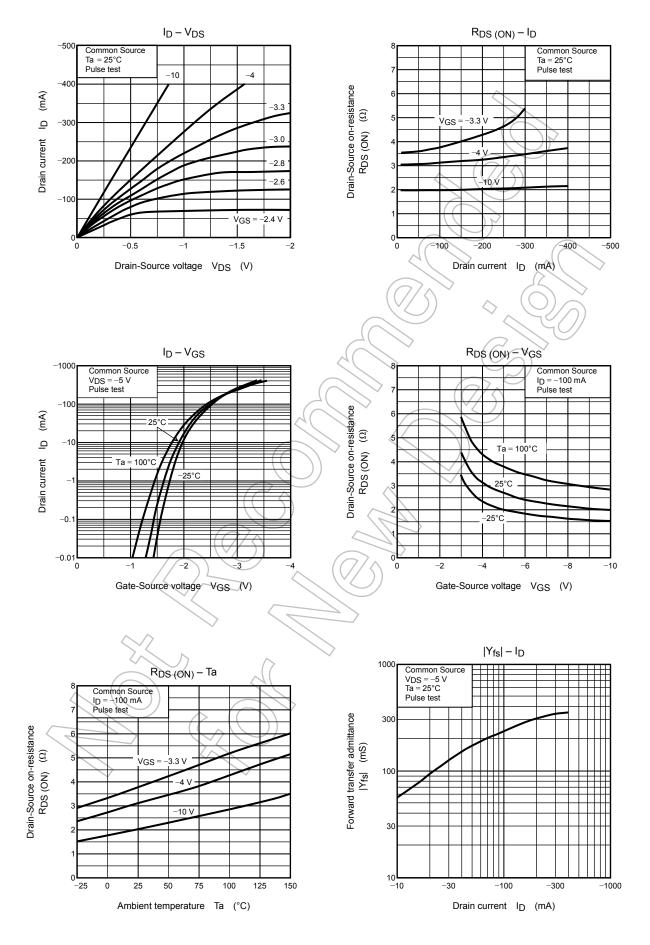
Q1 (Nch MOS FET)



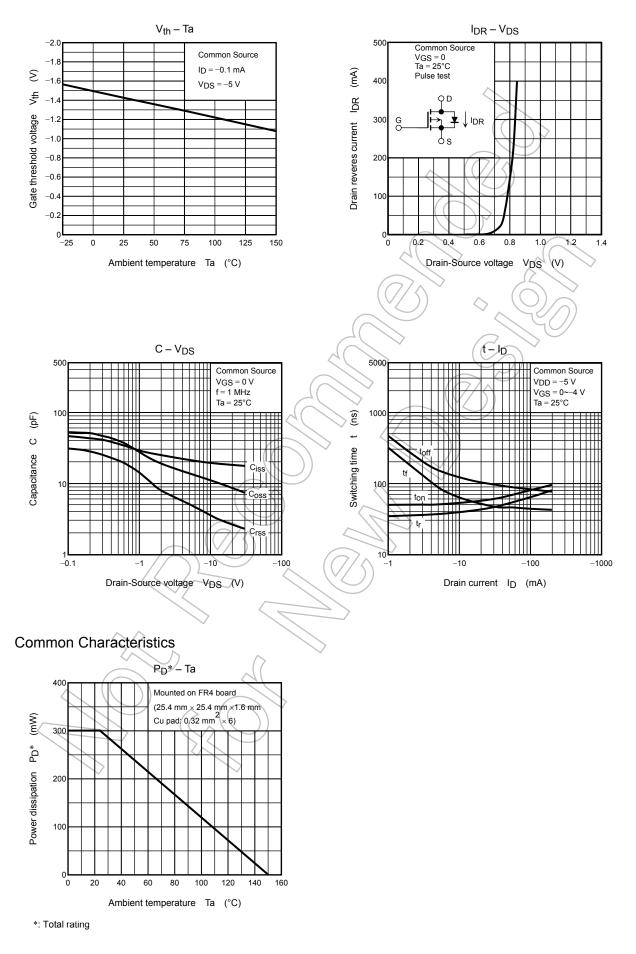
Q1 (Nch MOS FET)



Q2 (Pch MOS FET)



Q2 (Pch MOS FET)



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